

## **BZX55C Series**

## Zener diode

Voltage Range 2.4 to 75 Volts

#### **Features**

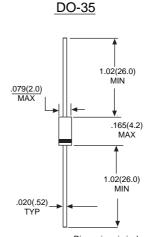
1.High reliability

# Applications Voltage stabilization

#### Construction

Silicon epitaxial planer

# Absoluto Maximum Ratings $_{Tj=25^{\circ}C}$



Dimensions in inches and (millimeters)

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Parameter	Test Conditions	Type	Symbol	Value	Unit
Power dissipation	I=4mm TL*25°C		PD	500	mW
Z-current			lz	PD/Vz	mA
Junction temperature			Tj	175	0C
Storage temperature range			Tstg	-65~+175	0C

### Maximum Thermal Resistance

Tj=250C

Parameter	Test Conditions	Symbol	Value	Unit
Junction ambient	I=4mm TL=constant	RthJA	500	K/W

### **Electrcal Characteristics**

Tj=250C

Parameter	Test Conditions	Туре	Symbol	Min	Тур	Max	Unit
Forward voltage	IF=200mA		VF			1.5	V



Туре	Vznom	lzt	for Vzr and	r	řzk a	t Izk	ln at	VR	TKvz
BZX55C	V	mA	V	*	*	mA	uA	V	%/k
2V4	2.4	5	2.28~2.56	<85	<600	1	<50	1	-0.09~-0.06
2V7	2.7	5	2.5~2.9	<85	<600	1	<10	1	-0.09~-0.06
3V0	3.0	5	2.8~3.2	<85	<600	1	<4	1	-0.08~-0.05
3V3	3.3	5	3.1~3.5	<85	<600	1	<2	1	-0.08~-0.05
3V6	3.6	5	3.4~3.8	<85	<600	1	<2	1	-0.08~-0.05
3V9	3.9	5	3.7~4.1	<85	<600	1	<2	1	-0.08~-0.05
4V3	4.3	5	4.0~4.6	<75	<600	1	<1	1	-0.06~-0.03
4V7	4.7	5	4.4~5.0	<60	<600	1	<0.5	1	-0.05~+0.02
5V1	5.1	5	4.8~5.4	<35	<550	1	<0.1	1	-0.02~+0.02
5V6	5.6	5	5.2~6.0	<25	<450	1	<0.1	1	-0.05~+0.05
6V2	6.2	5	5.8~6.6	<10	<200	1	<0.1	2	0.03~0.06
6V8	6.8	5	6.4~7.2	<8	<150	1	<0.1	3	0.03~0.07
7V5	7.5	5	7.0~7.9	<7	<50	1	<0.1	5	0.03~0.07
8V2	8.2	5	7.7~8.7	<7	<50	1	<0.1	6.2	0.03~0.08
9V1	9.1	5	8.5~9.6	<10	<50	1	<0.1	6.8	0.03~0.09
10	10	5	9.4~10.6	<15	<70	1	<0.1	7.5	0.03~0.1
11	11	5	10.4~11.6	<20	<70	1	<0.1	8.2	0.03~0.11
12	12	5	11.4~12.7	<20	<90	1	<0.1	9.1	0.03~0.11
13	13	5	12.4~14.1	<26	<110	1	<0.1	10	0.03~0.11
15	15	5	13.8~15.6	<30	<110	1	<0.1	11	0.03~0.11
16	16	5	15.3~17.1	<40	<170	1	<0.1	12	0.03~0.11
18	18	5	16.8~19.1	<50	<170	1	<0.1	13	0.03~0.11
20	20	5	18.8~21.2	<55	<220	1	<0.1	15	0.03~0.11
22	22	5	20.8~23.3	<55	<220	1	<0.1	16	0.04~0.12
24	24	5	22.8~25.6	<80	<220	1	<0.1	18	0.04~0.12
27	27	5	25.1~28.9	<80	<220	1	<0.1	20	0.04~0.12
30	30	5	28~32	<80	<220	1	<0.1	22	0.04~0.12
33	33	5	31~35	<80	<220	1	<0.1	24	0.04~0.12
36	36	5	34~38	<80	<220	1	<0.1	27	0.04~0.12
39	39	2.5	37~41	<90	<500	0.5	<0.1	30	0.04~0.12
43	43	2.5	40~46	<90	<600	0.5	<0.1	33	0.04~0.12
47	47	2.5	44~50	<110	<700	0.5	<0.1	36	0.04~0.12
51	51	2.5	48~54	<125	<700	0.5	<0.1	39	0.04~0.12
56	56	2.5	52~60	<135	<1000	0.5	<0.1	43	0.04~0.12
62	62	2.5	58~66	<150	<1000	0.5	<0.1	47	0.04~0.12
68	68	2.5	64~72	<200	<1000	0.5	<0.1	51	0.04~0.12
75	75	2.5	70~79	<250	<1500	0.5	<0.1	56	0.04~0.12

1)Tighter tolerances available request: BZX55A...\*1% of Vznom

BZ55B...\*2% of Vznor

2)at Tj=150°C





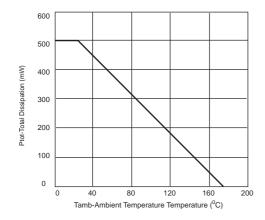


Figure 1.Total Power Dissipation vs. Ambient Temperature

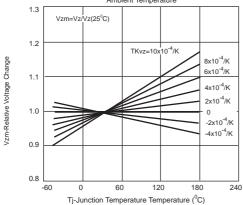
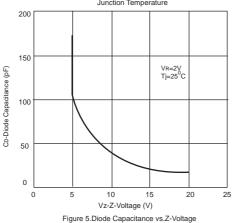


Figure 3.Typical of Working Voltage vs. Junction Temperature



1000 T<sub>j=25°C</sub> 100 T<sub>j=25°C</sub> 10 I<sub>z=5mA</sub> 10 I<sub>z=5mA</sub> 10 I<sub>z=5mA</sub> 10 V<sub>z-Z-Voltage</sub> (V)

Figure 2. Typical Change of Working Voltage under Operating Conditions at Tamb=25-C

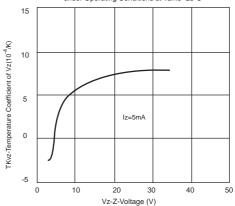


Figure 4. Temperature Conefficient of Vz vs. Z-Volltage



